

View Online at <https://aerobasegroup.com/nsn/5961-00-238-6889>

Inclosure Material:

Metal all transistor

Overall Length:

0.210 inches all transistor

Terminal Length:

0.500 inches all transistor

Overall Diameter:

0.209 inches all transistor and 0.230 inches all transistor

Internal Configuration:

Field effect all transistor

Channel Polarity And Control Type (non-core):

P-channel junction type 2nd transistor

Component Function Relationship:

Matched

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal all transistor

Terminal Circle Diameter:

0.100 inches all transistor

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

50.0 drain to gate voltage 1st transistor and 50.0 forward gate to source voltage 1st transistor

Current Rating Per Characteristic:

50.00 milliamperes source cutoff current minor all transistor

Power Rating Per Characteristic:

300.0 milliwatts small-signal input power, common-collector absolute all transistor

Maximum Operating Temperature Per Measurement Point:

175.0 degrees celsius junction all transistor

Terminal Type And Quantity:

4 uninsulated wire lead all transistor

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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